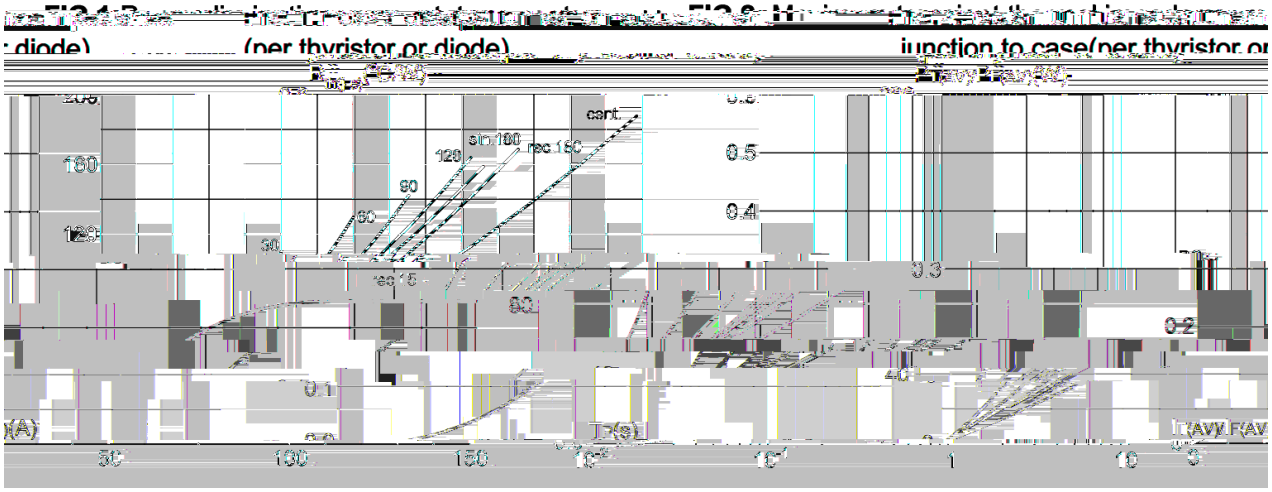
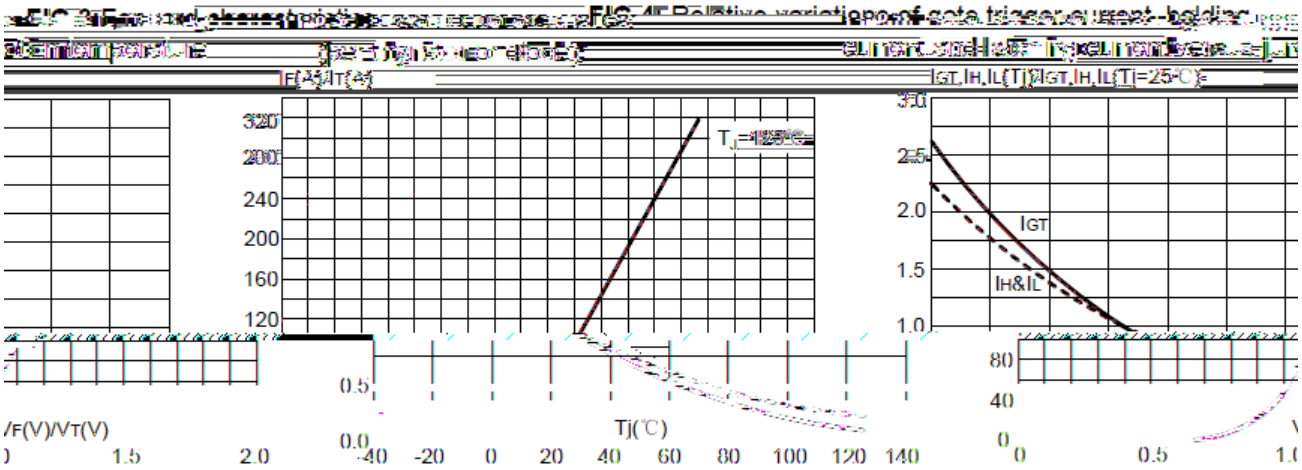
	℃					
	℃					
	℃					
	℃					
	℃					
	℃					
	℃					
	℃					

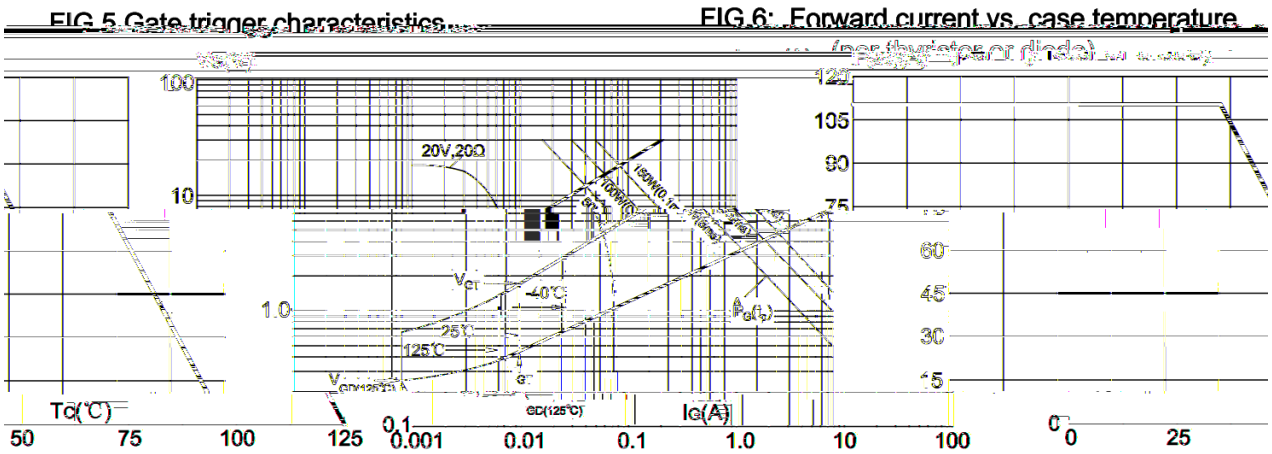
			±		



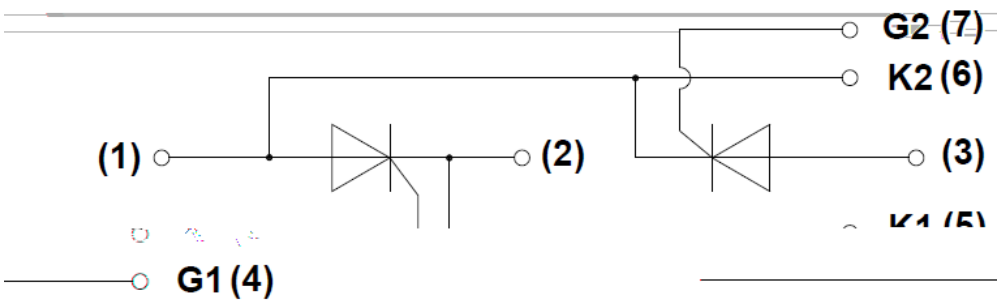
(per thyristor or diode)
junction to case(per thyristor or
cant.
sin.180
rec.180

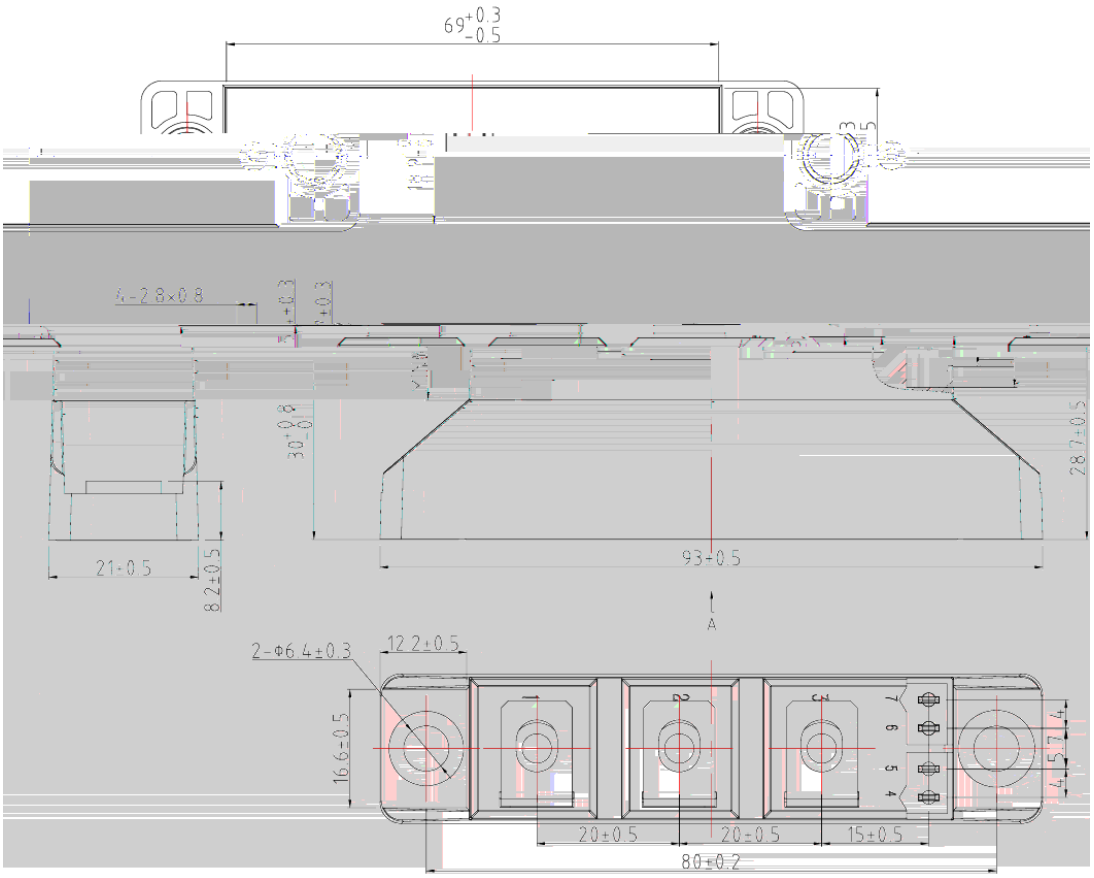


IGT
IH&IL
Tj(℃)



20V,20Ω
Tc(℃)
IG(A)


G2 (7)
K2 (6)
(1)
(2)
(3)
G1 (4)


69+0.3 -0.5
4-2.8×0.8
21±0.5
8.2±0.5
93±0.5
A
2-Φ6.4±0.3
12.2±0.5
16.6±0.5
20±0.5
20±0.5
15±0.5
80±0.2